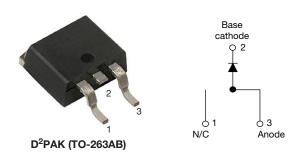


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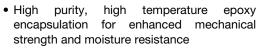
High Performance Schottky Rectifier, 15 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	15 A						
V _R	35 V, 40 V, 45 V						
V _F at I _F	0.50 V						
I _{RM} max.	70 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	16 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201, class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-12TQ...SHM3 Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	15	Α						
V _{RRM}	Range	35 to 45	V						
I _{FSM}	$t_p = 5 \mu s sine$	990	Α						
V _F	15 A _{pk} , T _J = 125 °C	0.50	V						
T _J	Range	-55 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-12TQ035SHM3	VS-12TQ040SHM3	VS-12TQ045SHM3	UNITS			
Maximum DC reverse voltage	V_{R}	35	40	45	V			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 120 °C	15	А			
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	990	A		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	250			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2.4 \text{A}, L = 5.5 \text{G}$	16	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximo	2.4	Α			

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum forward voltage drop See fig. 1		15 A	T _{.1} = 25 °C	0.56			
	V _{FM} ⁽¹⁾	30 A	1J=25 C	0.71	V		
	VFM (**)	15 A	- T _{.1} = 125 °C	0.50			
		30 A	1J = 125 C	0.64			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	1.75	mA		
See fig. 2		T _J = 125 °C	VR = nateu VR	70	IIIA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	900	рF			
Typical series inductance	L _S	Measured lead to lead 5 r	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

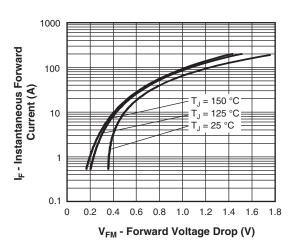
Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and stemperature range	torage	T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistation to case	ance,	R_{thJC}	DC operation See fig. 4	2.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W			
Annuarimenta weight				2	g			
Approximate weight				0.07	OZ.			
Marinting toward	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style D ² PAK	12TQ0 12TQ0 12TQ0	040SH			

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1000 I_R - Reverse Current (mA) 100 150 °C = 125 °C T_{.1} = 100 °C 75 °C 0.1 = 50 °C 0.01 25 °C 0.001 20 25 30 0 10 15 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

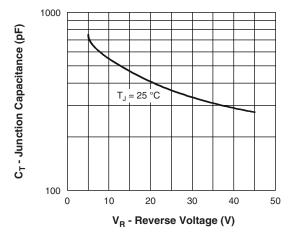


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

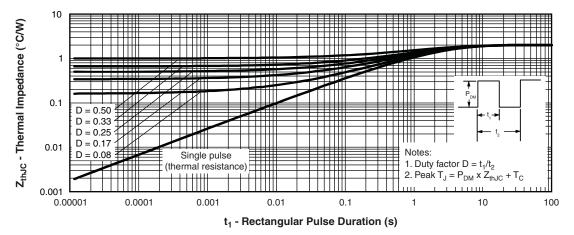


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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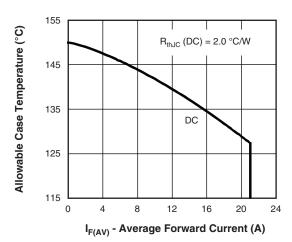


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

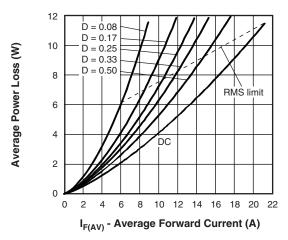


Fig. 6 - Forward Power Loss Characteristics

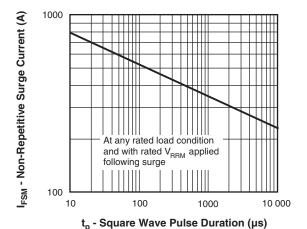


Fig. 7 - Maximum Non-Repetitive Surge Current

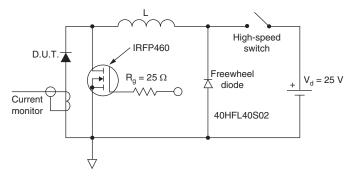
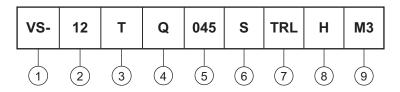


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

Package: T = TO-220, D²PAK

- Schottky "Q" series 035 = 35 V

- Voltage ratings — 040 = 40 V 045 = 45 V

7 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-12TQ035SHM3	50	1000	Antistatic plastic tubes						
VS-12TQ035STRRHM3	800	800	13" diameter reel						
VS-12TQ035STRLHM3	800	800	13" diameter reel						
VS-12TQ040SHM3	50	1000	Antistatic plastic tubes						
VS-12TQ040STRRHM3	800	800	13" diameter reel						
VS-12TQ040STRLHM3	800	800	13" diameter reel						
VS-12TQ045SHM3	50	1000	Antistatic plastic tubes						
VS-12TQ045STRRHM3	800	800	13" diameter reel						
VS-12TQ045STRLHM3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?95032					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS INC		INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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